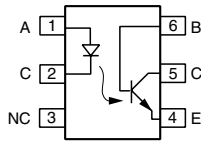
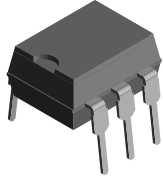
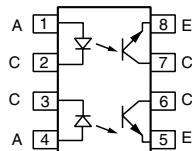
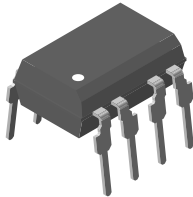


## Optocoupler, Phototransistor Output (Single, Dual, Quad Channel)

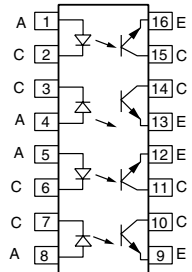
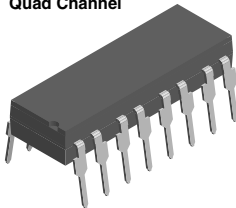
Single Channel



Dual Channel



Quad Channel



1179015

### FEATURES

- IL74/ILD74/ILQ74 TTL compatible
- Transfer ratio, 35 % typical
- Coupling capacitance, 0.5 pF
- Single, dual, and quad channel
- Industry standard DIP packages
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 pending available with option 1, X001 suffix
- FIMKO

### DESCRIPTION

The IL74/ILD74/ILQ74 is an optically coupled pair with a GaAlAs infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The IL74/ILD74/ILQ74 is especially for driving medium-speed logic, where it may be used to eliminate troublesome ground loop and noise problems. Also it can be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CTR modulation.

The ILD74 has two isolated channels in a single DIP package; the ILQ74 has four isolated channels per package.

ORDER INFORMATION	
PART	REMARKS
IL74	CTR <sub>DC</sub> > 12.5 %, single channel DIP-6
ILD74	CTR <sub>DC</sub> > 12.5 %, dual channel DIP-8
ILQ74	CTR <sub>DC</sub> > 12.5 %, quad channel DIP-16
IL74-X006	CTR <sub>DC</sub> > 12.5 %, single channel DIP-6 400 mil (option 6)
ILD74-X006	CTR <sub>DC</sub> > 12.5 %, dual channel DIP-8 400 mil (option 6)
ILD74-X007	CTR <sub>DC</sub> > 12.5 %, dual channel SMD-8 (option 7)
ILD74-X009	CTR <sub>DC</sub> > 12.5 %, dual channel SMD-8 (option 9)
ILQ74-X009	CTR <sub>DC</sub> > 12.5 %, dual channel SMD-16 (option 9)

#### Note

For additional information on the available options refer to option information.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
<b>INPUT</b>					
Peak reverse voltage			$V_R$	3.0	V
Forward continuous current			$I_F$	60	mA
Power dissipation			$P_{diss}$	100	mW
Derate linearly from 55 %				1.33	mW/°C
<b>OUTPUT</b>					
Collector emitter breakdown voltage			$BV_{CEO}$	20	V
Emitter collector breakdown voltage			$BV_{ECO}$	5.0	V
Collector base breakdown voltage			$BV_{CBO}$	70	V
Power dissipation			$P_{diss}$	150	mW
Derate linearly from 25 °C				2.0	mW/°C
<b>COUPLER</b>					
Isolation test voltage	$t = 1.0 \text{ s}$		$V_{ISO}$	5300	$V_{RMS}$
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ °C}$		$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500 \text{ V}, T_{amb} = 100 \text{ °C}$		$R_{IO}$	$\geq 10^{11}$	$\Omega$
Total package dissipation		IL74	$P_{tot}$	200	mW
		ILD74	$P_{tot}$	400	mW
		ILQ74	$P_{tot}$	500	mW
Derate linearly from 25 °C		IL74		2.7	mW/°C
		ILD74		5.33	mW/°C
		ILQ74		6.67	mW/°C
Creepage distance				$\geq 7.0$	mm
Clearance distance				$\geq 7.0$	mm
Storage temperature			$T_{stg}$	- 55 to + 150	°C
Operating temperature			$T_{amb}$	- 55 to + 100	°C
Lead soldering time at 260 °C				10	s

**Note**

$T_{amb} = 25 \text{ °C}$ , unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		1.3	1.5	V
Reverse current	$V_R = 3.0 \text{ V}$	$I_R$		0.1	100	$\mu\text{A}$
Capacitance	$V_R = 0 \text{ V}$	$C_O$		25		pF
<b>OUTPUT</b>						
Collector emitter breakdown voltage	$I_C = 1.0 \text{ mA}$	$BV_{CEO}$	20	50		V
Collector emitter leakage current	$V_{CE} = 5.0 \text{ V}, I_F = 0 \text{ A}$	$I_{CEO}$		5.0	500	nA
Capacitance collector emitter	$V_{CE} = 0 \text{ V}, f = 1.0 \text{ Hz}$	$C_{CE}$		10		pF
<b>COUPLER</b>						
Saturation voltage, collector emitter	$I_C = 2.0 \text{ mA}, I_F = 16 \text{ mA}$	$V_{CEsat}$		0.3	0.5	V
Resistance (input to output)		$R_{IO}$		100		$G\Omega$
Capacitance (input to output)		$C_{IO}$		0.5		pF

**Note**

$T_{amb} = 25 \text{ °C}$ , unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

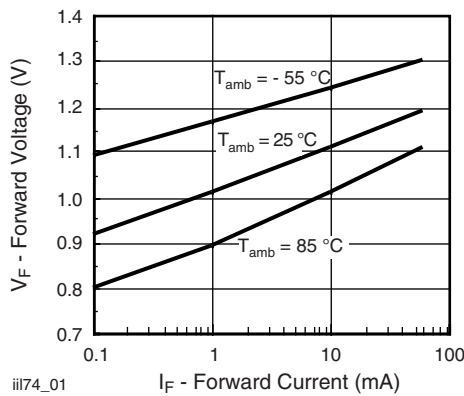


CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
DC current transfer ratio	$I_F = 16 \text{ mA}$ , $V_{CE} = 5.0 \text{ V}$	$CTR_{DC}$	12.5	35		%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Switching times	$R_L = 100 \Omega$ , $V_{CE} = 10 \text{ V}$ , $I_C = 2.0 \text{ mA}$	$t_{on}$ , $t_{off}$		3.0		$\mu\text{s}$

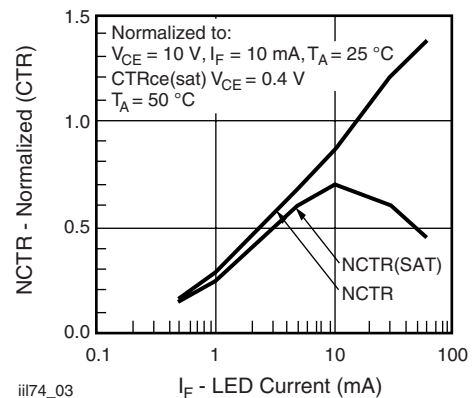
**TYPICAL CHARACTERISTICS**

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified



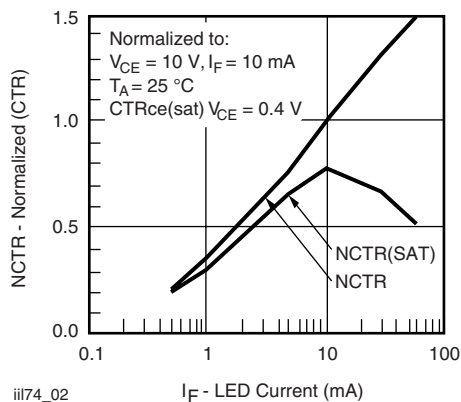
iii74\_01

Fig. 1 - Forward Voltage vs. Forward Current



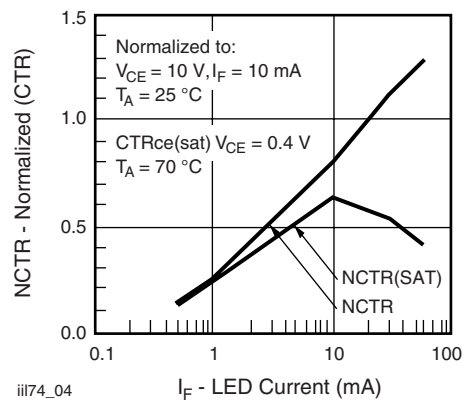
iii74\_03

Fig. 3 - Normalized Non-Saturated and Saturated CTR vs. LED Current



iii74\_02

Fig. 2 - Normalized Non-Saturated and Saturated CTR vs. LED Current



iii74\_04

Fig. 4 - Normalized Non-Saturated and Saturated CTR vs. LED Current

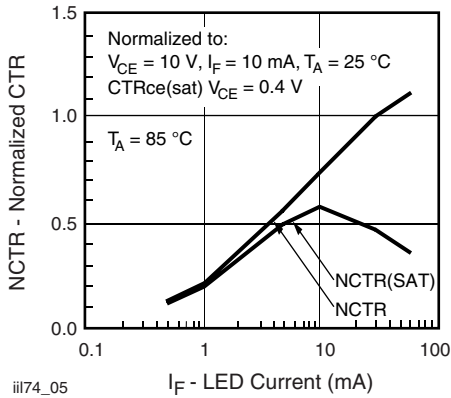


Fig. 5 - Normalized Non-Saturated and Saturated CTR vs. LED Current

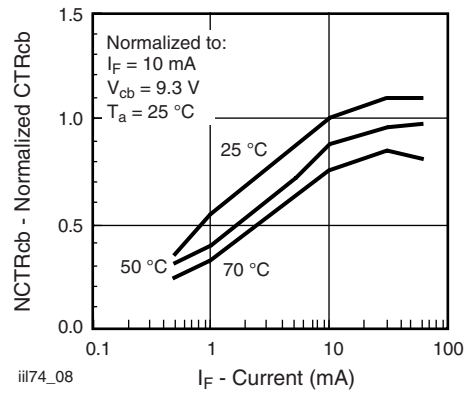


Fig. 8 - Normalized  $CTR_{cb}$  vs. LED Current and Temperature

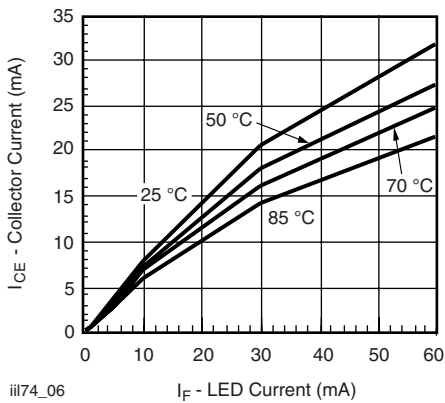


Fig. 6 - Collector Emitter Current vs. Temperature and LED Current

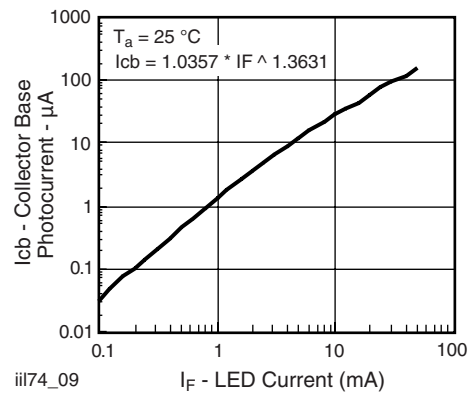


Fig. 9 - Collector Base Photocurrent vs. LED Current

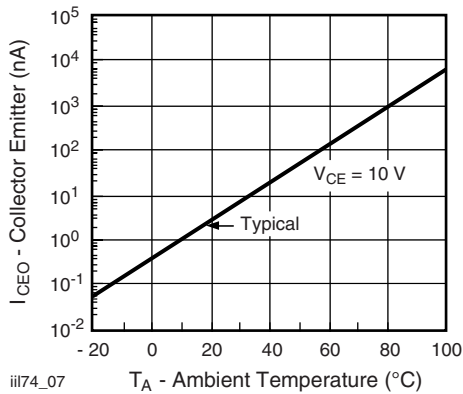


Fig. 7 - Collector Emitter Leakage Current vs. Temperature

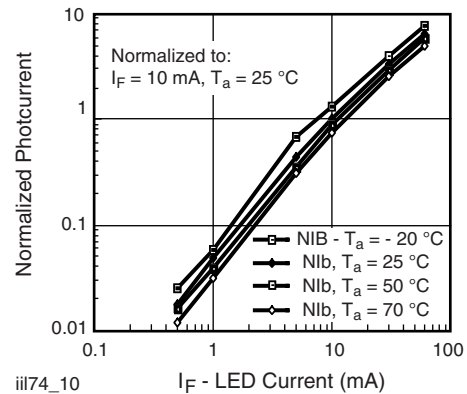


Fig. 10 - Normalized Photocurrent vs.  $I_F$  and Temperature

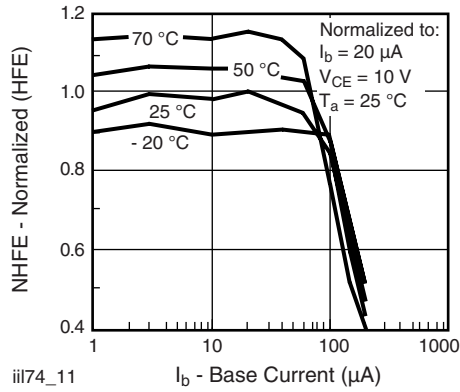
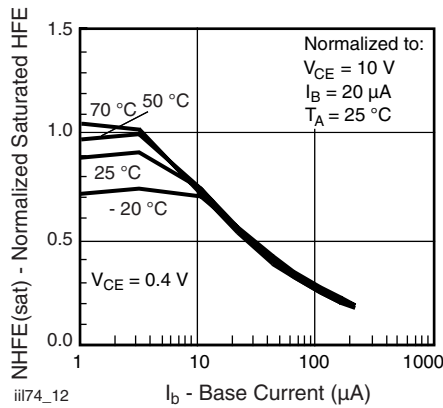
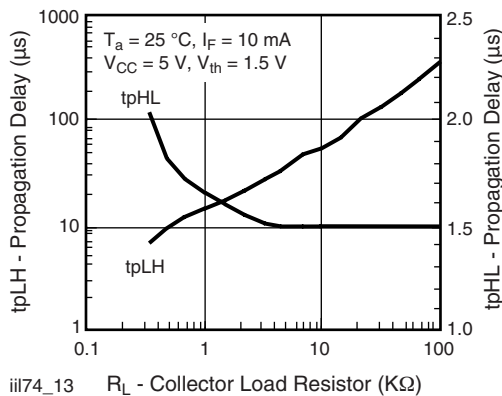

 Fig. 11 - Normalized Non-Saturated  $h_{FE}$  vs. Base Current and Temperature

 Fig. 12 - Normalized Saturated  $h_{FE}$  vs. Base Current and Temperature


Fig. 13 - Propagation Delay vs. Collector Load Resistor

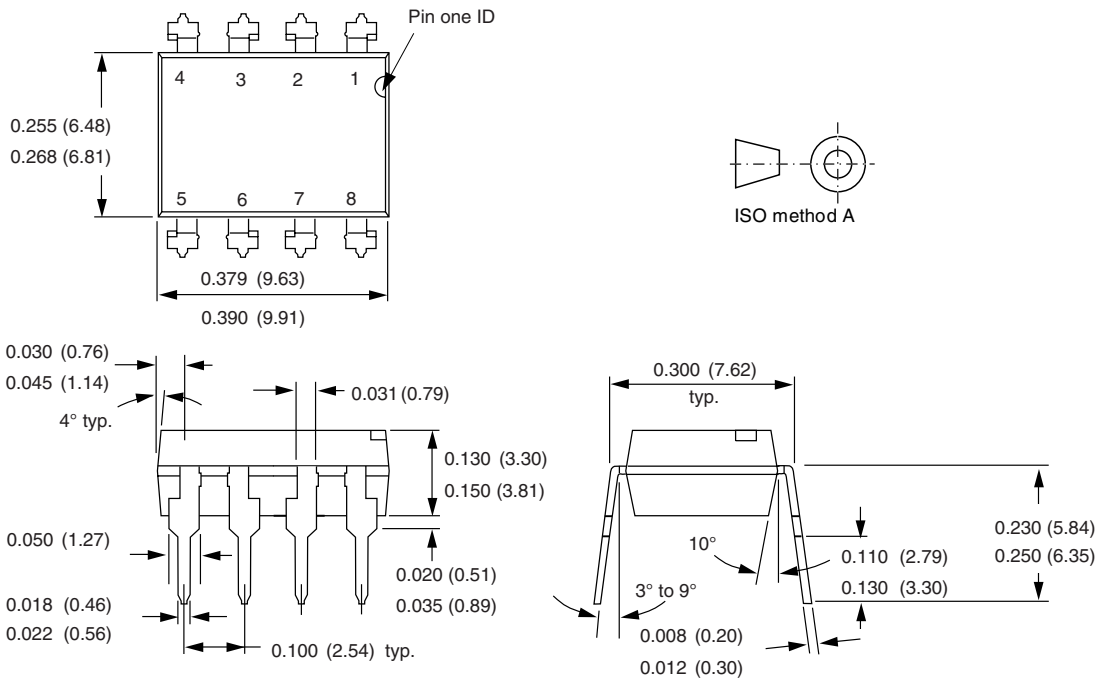
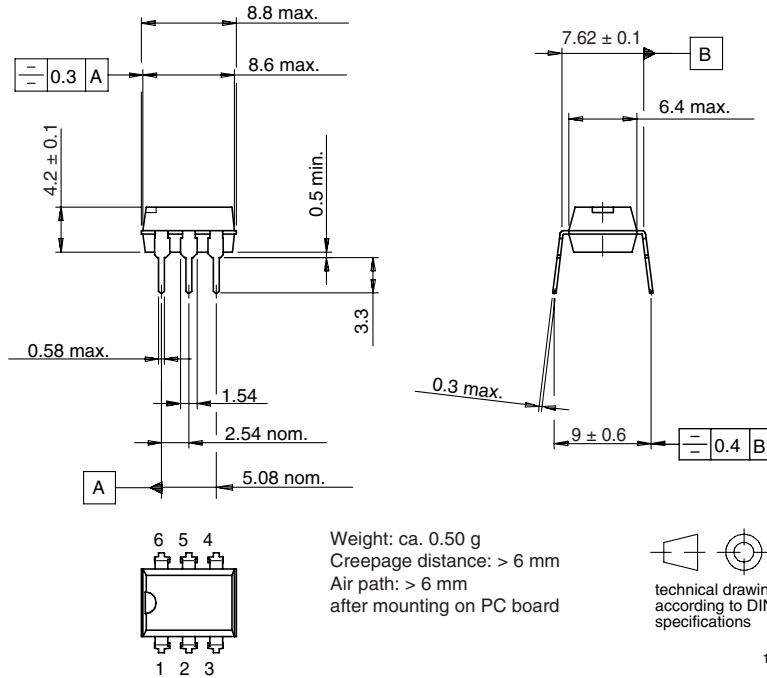
# IL74/ILD74/ILQ74

Vishay Semiconductors

Optocoupler, Phototransistor Output  
(Single, Dual, Quad Channel)



## PACKAGE DIMENSIONS in inches (millimeters)

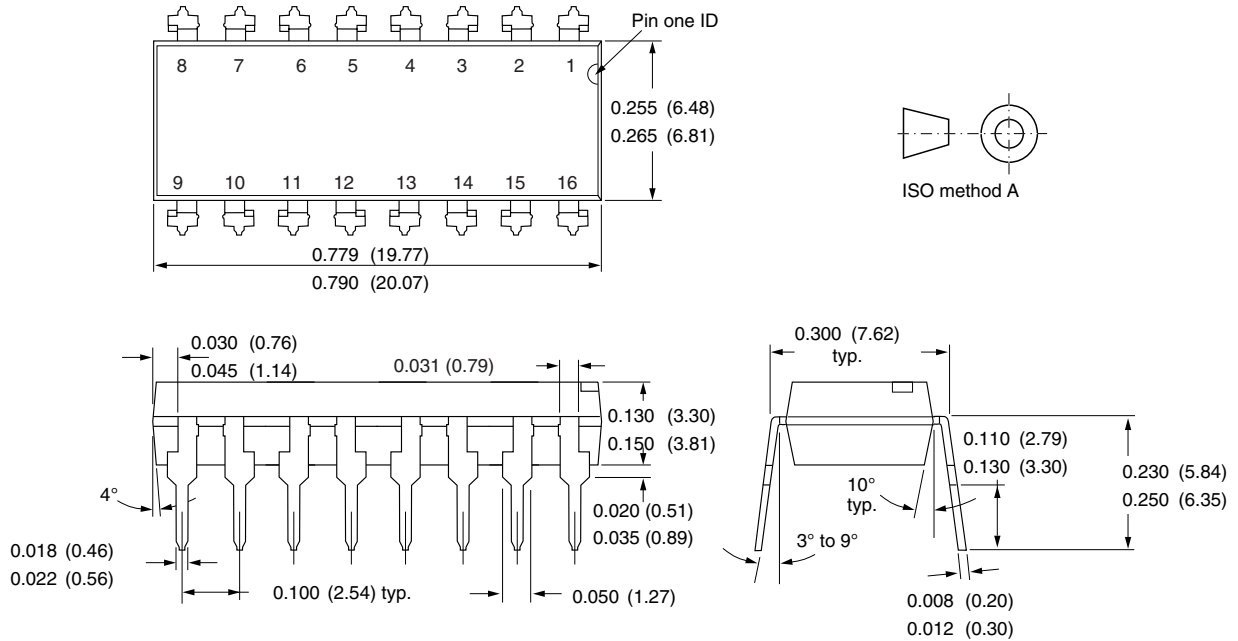


i178006



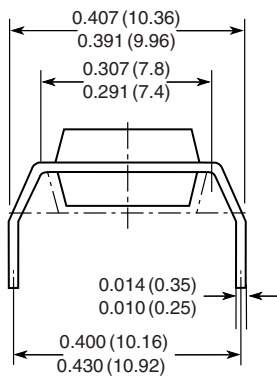
# Optocoupler, Phototransistor Output (Single, Dual, Quad Channel)

# IL74/ILD74/ILQ74 Vishay Semiconductors

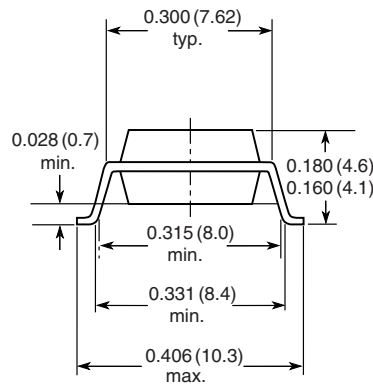


i178007

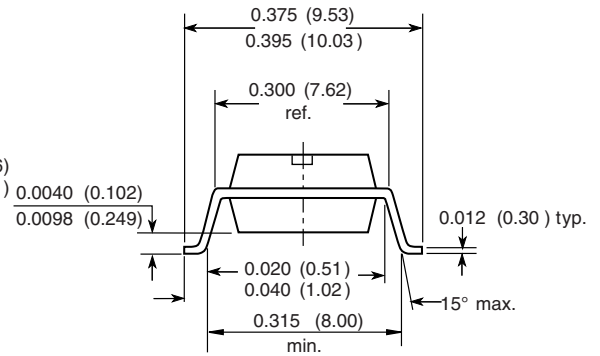
## Option 6



## Option 7



## Option 9



18450



## **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany





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- Экспресс доставка в любую точку России;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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